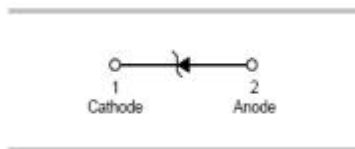


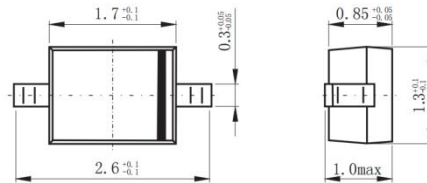
Features

- Wide zener voltage range selection: 2.4V to 51V .
- VZ Tolerance selection of $\pm 2\%$ (B series).
- Ideally suited for automated assembly processes.
- Moisture sensitivity level 1.

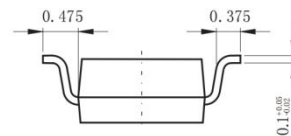


Applications

- Zener diode.
- Ultra-small surface mount package.



SOD-323



Dimensions in inches and (millimeters)

Ordering Information

Type No.	Marking	Package Code
BZT52B2V4S-BZT52B51S	See table 2	SOD-323

MAXIMUM RATING @ $T_a=25^{\circ}\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Forward Voltage @ $I_F=10\text{mA}$	V_F	0.9	V
Power Dissipation	P_d	200	mW
Thermal resistance, junction to ambient air	$R_{\theta JA}$	625	$^{\circ}\text{C}/\text{W}$
Junction temperature	T_j	150	$^{\circ}\text{C}$
Storage temperature range	T_{stg}	-65 to +150	$^{\circ}\text{C}$

Notes: These ratings are limiting values above which the serviceability of the diodes may be impaired.



ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Type Number	Marking Code	Zener Voltage Range				Maximum Zener Impedance			Maximum Reverse Current	
		Vz@IzT			IzT	ZzT@IzT	IzK	ZzK@IzK	IR	@VR
		Nom(V)	Min(V)	Max(V)	mA	Q	mA	Q	PA	V
BZT52B2V4S	2WX	2.4	2.35	2.45	5	94	1	564	45	1
BZT52B2V7S	2W1	2.7	2.65	2.75	5	94	1	564	18	1
BZT52B3V0S	2W2	3.0	2.94	3.06	5	89	1	564	9	1
BZT52B3V3S	2W3	3.3	3.23	3.37	5	89	1	564	4.5	1
BZT52B3V6S	2W4	3.6	3.53	3.67	5	84	1	564	4.5	1
BZT52B3V9S	2W5	3.9	3.82	3.98	5	84	1	564	2.7	1
BZT52B4V3S	2W6	4.3	4.21	4.39	5	84	1	564	2.7	1
BZT52B4V7S	2W7	4.7	4.61	4.79	5	75	1	564	2.7	2
BZT52B5V1S	2W8	5.1	5.00	5.20	5	56	1	470	1.8	2
BZT52B5V6S	2W9	5.6	5.49	5.71	5	37	1	451	0.9	2
BZT52B6V2S	2WA	6.2	6.08	6.32	5	9	1	376	2.7	4
BZT52B6V8S	2WB	6.8	6.66	6.94	5	14	1	141	1.8	4
BZT52B7V5S	2WC	7.5	7.35	7.65	5	14	1	75	0.9	5
BZT52B8V2S	2WD	8.2	8.04	8.36	5	14	1	75	0.63	5
BZT52B9V1S	2WE	9.1	8.92	9.28	5	14	1	94	0.45	6
BZT52B10S	2WF	10	9.80	10.20	5	18	1	141	0.18	7
BZT52B11S	2WG	11	10.78	11.22	5	18	1	141	0.09	8
BZT52B12S	2WH	12	11.76	12.24	5	23	1	141	0.09	8
BZT52B13S	2WI	13	12.74	13.26	5	28	1	160	0.09	8
BZT52B15S	2WJ	15	14.70	15.30	5	28	1	188	0.045	10.5
BZT52B16S	2WK	16	15.68	16.32	5	37	1	188	0.045	11.2
BZT52B18S	2WL	18	17.64	18.36	5	42	1	212	0.045	12.6
BZT52B20S	2WM	20	19.60	20.40	5	51	1	212	0.045	14.0
BZT52B22S	2WN	22	21.56	22.44	5	51	1	235	0.045	15.4
BZT52B24S	2WO	24	23.52	24.48	5	65	1	235	0.045	16.8
BZT52B27S	2WP	27	26.46	27.54	5	75	0.5	282	0.045	18.9
BZT52B30S	2WQ	30	29.40	30.60	5	75	0.5	282	0.045	21.0

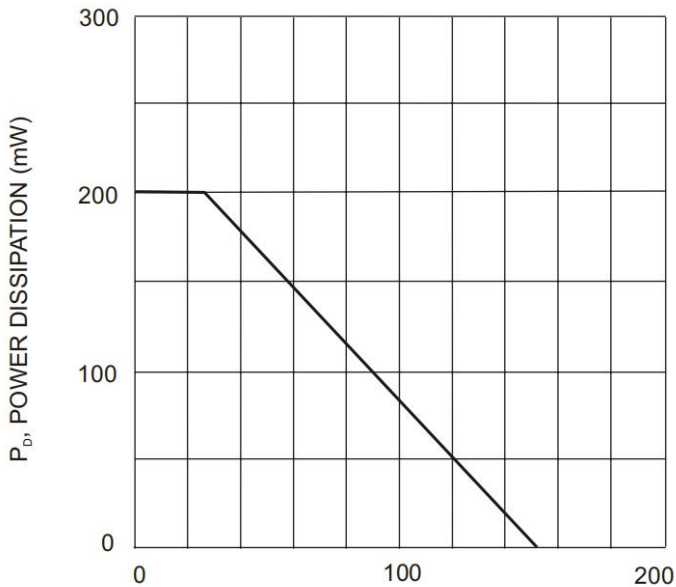


BZT52B33S	2WR	33	32.34	33.66	5	75	0.5	306	0.045	23.0
BZT52B36S	2WS	36	35.28	36.72	5	84	0.5	329	0.045	25.2
BZT52B39S	2WT	39	38.22	39.78	5	122	0.5	329	0.045	27.3
BZT52B43S	2WU	43	42.14	43.86	5	141	0.5	353	0.045	30.1
BZT52B47S	2WV	47	46.06	47.94	5	160	0.5	353	0.045	33.0
BZT52B51S	2WW	51	49.98	52.02	5	169	0.5	376	0.045	35.7

Notes:1.The zener voltage (VZ) is tested under pulse condition of 10ms.

2. The device numbers listed have a standard tolerance on the nominal zener voltage of $\pm 2\%$.
3. The zener impedance is derived from the 60-cycle ac voltage, which results when an ac current having an rms value equal to 10% of the dc zener current (I_{ZT} or I_{ZK}) is superimposed to I_{ZT} or I_{ZK} .

TYPICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified



T_A , AMBIENT TEMPERATURE, $^\circ\text{C}$
Fig. 1. Power Derating Curve

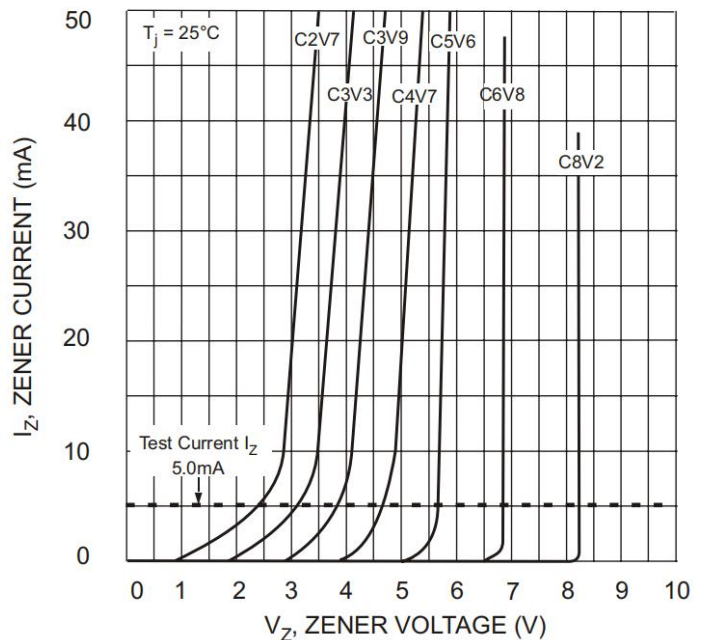


Fig. 2 Zener Breakdown Characteristics

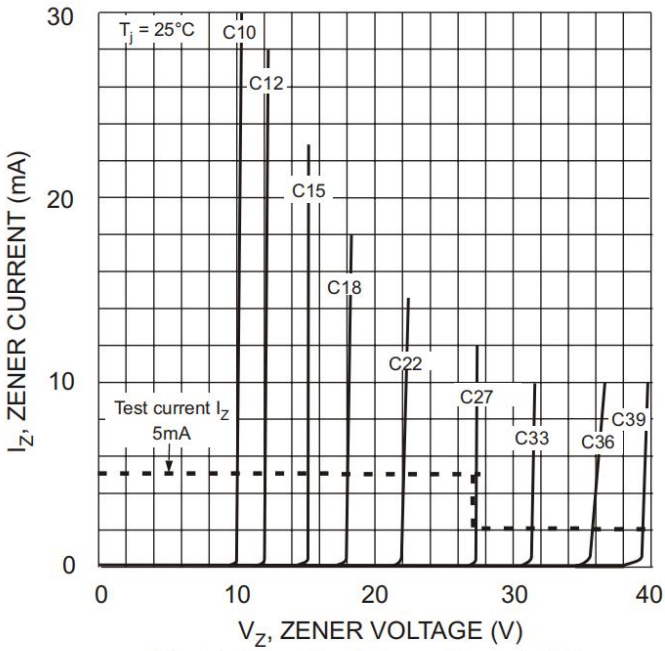


Fig. 3. Zener Breakdown Characteristics

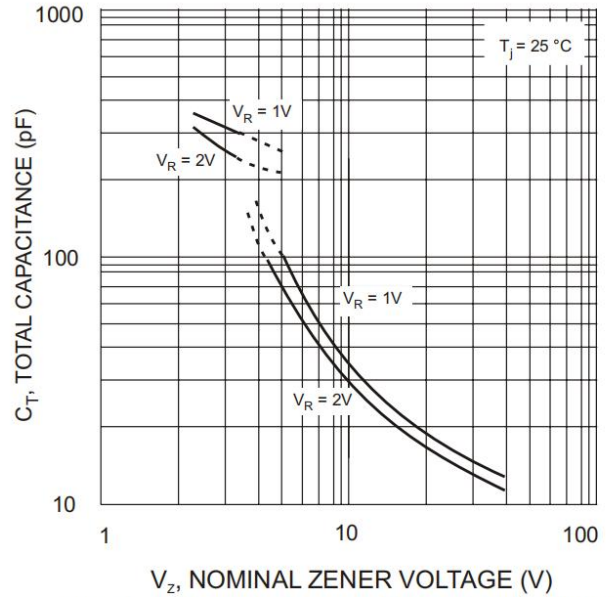


Fig. 4. Total Capacitance vs Nominal Zener Voltage

PACKAGE	SPQ/PCS	CARTON SPQ/PCS	CARTON SIZE/CM	CARTON GW/KG	CARTON NW/KG
SOD- 323	3000/REEL	180000	44X44X22	9.00	8.00